# IBIS Interconnect SPICE Subcircuits Specification 

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## Statement of Changes

- Eliminated or reduced use of terms: token, netlist, command, you
- Defined or refined existing definitions for key concepts: statement, token, delimiter
- Added table of contents and imposed formatting (as defined under "Conventions") to clarify relationships and hierarchies
- Added skeleton text for .subcircuit and .model definitions
- Standardized (for the most part) fonts, typefaces and other visual aspects of the document per "Conventions" section
- Removed portions of the document conventions that were unused
- Reordered some minor portions of the document to better accommodate the flow (more like a narrative)
- Clarified existing examples, particularly for comments and expressions
- Added parameter description text to support strings
- Clarified line continuation text
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## 1. Overview

The IBIS Open Forum, in order to enable easier data exchange between users of signal/power integrity simulation and physical layout/routing software tools, is issuing a generic netlist format, to be called "IBIS Interconnect SPICE Subcircuits" (IBIS-ISS).

This format is similar in structure and major functions to the SPICE (Simulation Program with Integrated Circuit Emphasis) nodal syntax developed at the University of California at Berkeley and since implemented in various forms by individual software tool vendors. IBIS-ISS is the first industry-wide attempt to standardize SPICE subcircuit representation.

This version of IBIS-ISS is based on a subset of HSPICE $\circledR^{\circledR}$, used with permission from Synopsys, Inc. HSPICE is a registered trademark of Synopsys, Inc.

## 2.Goals and Scope

The syntax of IBIS-ISS is intended to:

- describe interconnect structures (such as PCB traces, connectors, cables, etc.) electrically, for analysis in a signal integrity and/or power integrity context
- describe the arrangement or topology of interconnect structures, as they relate to each other and to active devices in a system

To these ends, IBIS-ISS includes support for:

- elementary circuit elements (resistors, capacitors, inductors)
- transmission line elements (lossless and lossy)
- frequency-domain network parameters (e.g., S-parameters)
- parameter/variable passing to elements and subcircuits
- dependent sources
- string-based node naming
- user-defined comments
- abstraction through modular, user-defined subcircuit definitions

IBIS-ISS does NOT include or cover:

- descriptions of complete netlists intended for input "as-is" to simulation tools
- model formats or "process cards" for active devices (e.g., diodes, transistors)
- independent sources
- controls or options for any simulation engine (e.g., precision, algorithm selection)
- simulation or analysis types (e.g., DC, transient)
- sweep or run control (e.g., Monte Carlo)
- geometrical descriptions for field solvers
- support for other kinds of data extraction/export (e.g., S-parameter generation)
- measurement, printing or probing
- encryption support

3. 

## 4.Conventions

The following typographical conventions are used in IBIS-ISS. Note that these may be combined (e.g., Courier font in bold type).

Table 1: Document Conventions

| Convention | Description |
| :--- | :--- |
| Courier | Indicates statement syntax. |
| Italic | Indicates a user-defined value, where a specific text string <br> will replace the italics shown in an actual IBIS-ISS file (e.g., <br> Rxxxx is a generic representation of a resistor element <br> name, such as Rname). |
| Bold | Indicates verbatim text in syntax and examples |
| [] | Denotes optional tokens <br> Indicates that tokens of the same type may be added as <br> appropriate to the element structure: <br> pin1 pin2 ... pin |
| $\ldots$ | Indicates a choice among defined alternatives, such as <br> low \| medium | high |
| I | Indicates a continuation of a statement across input lines. <br> Note that continuation may only be used between tokens <br> and shall not split any single token across lines. |
| + |  |

## 5. Input Structure and Data Entry

This section describes the input file and structures for representing input data.

## 1. Input File Guidelines

An input file consists of a collection of statements describing a portion of a complete circuit. This input file is intended for inclusion in a larger netlist or description of a complete circuit, to be used by a simulation tool.

An input filename may be up to 1024 characters long. The input file shall be in ASCII format (insert IEEE or ANSI definition here). The input file shall not be in a binary, packed or compressed format.

## 2. Statements and Tokens

A statement in IBIS-ISS is a text string consisting of tokens and delimiters. An IBIS-ISS file may contain multiple statements (the number of statements is not limited by the IBIS-ISS definition, but may be limited by the computer architecture and/ or operating system used to process the file).
Any individual input statement may be up to 1024 characters long.
Statements in an input file may appear in any order.
Any valid string of characters between two token delimiters is a token.
For the purpose of this specification, statements are grouped into the following types:

- Element instances
- Parameter definitions
- File includes
- Subcircuit definitions
- Model definitions
- Comments
- Subcircuit ending statements

Subcircuit ending statements, subcircuit definitions, model definitions, parameter definitions and file includes all begin with the dot (.) character.
The specific syntax of the above statement types are described in the sections below.

- IBIS-ISS ignores differences between upper and lower case in input statements, except in quoted filenames.
- To continue a statement across multiple lines, the plus (+) sign shall be used as the first non-numeric, non-blank character of each continued line. The + sign shall be used only between tokens and token delimiters and never to split tokens.
- Tokens with extended length (such as paths and expressions) may span multiple lines using a single whitespace character followed by either a backslash ( $\backslash$ ) or a double backslash ( $\backslash \backslash$ ) at the end of the line containing the token to be continued on the following line. Note that quoted strings may only be continued using the double backslash ( $\backslash 1$ ) sequence.
- The following characters are reserved for special use and shall not be used as part of any parameter or node name:

$$
()="
$$

- The following strings are reserved for special use and shall not be used as part of any parameter or node name in the associated element:

| Element | Reserved Operators |
| :--- | :--- |
| Capacitor | POLY, TC, SENS |
| E/G-element | AND, DELAY, FOSTER, LAPLACE, <br> NAND, NPWL, NOR, VCCS, OPAMP, <br> OR, POLE, POLY, PWL, SPUR, <br> TRANSFORMER, VCR, VCCAP, VCVS, <br> FREQ, ZTRANS, VMRF, NOISE, <br> NOISEFILE, MNAME, PHASE, SCALE, <br> MAX, PAR |
| F/H-elements | POLY, PWL, AND, NAND, OR, NOR, <br> VMRF, CCCS, CCVS, DELAY |
| Port element | SIN, PU, PWL, EXP, PULSE, PE, SFFM, <br> AM, PAT, PL, HB, HBAC, DATA, AC, <br> DC, <br> LSAC, SNAC, PHOTO, NEUT, COS, |
| Inductor | VMRF, LFSR, PUL, HBLIN, R, <br> BITSTREAM, <br> PWLFILE, MOD, FILTER |
| Resistor | POLY, TC, SENS, RELUCTANCE, |


| S-element | ZO, ZO, MNAME |
| :--- | :--- |
| T/U- element | IC |
| W-element | RLGCFILE, PRINTZO, <br>  <br>  <br>  <br>  <br>  <br>  <br>  <br>  <br> RLGCMODEL,TABLEMODEL, <br> FSMODEL, UMODEL,, <br> SMODEL |

## 3. Special Characters

The following table lists the special characters that may be used as part of node names, element parameter names, and element instance names. For detailed discussion, see the appropriate sections in this chapter.

Note:
To avoid unexpected results or error messages, do not use the following mathematical characters in a parameter name in IBIS-ISS: * - + ^ and $/$.

Table 2: IBIS-ISS / Netlist Special Characters

| Special Character* |  | Node Name | Instance <br> Name** | Parameter Name** | Comments |
| :--- | :--- | :--- | :--- | :--- | :--- |
| $\sim$ | tilde | Legal <br> anywhere | Included only | Included only | n/a |
| $\boldsymbol{l}$ | exclamation <br> point | Legal <br> anywhere | Included only | Included only | n/a |
| @ | at sign | Legal <br> anywhere | Included only | Included only | n/a |
| \# | pound sign | Legal <br> anywhere | Included only | Included only | n/a |
| \$ | dollar sign | Included only <br> (avoid if after a <br> number in node <br> name) | Included only | Included only | In-line comment <br> character |


| \% | percent | Legal anywhere | Included only | Included only | n/a |
| :---: | :---: | :---: | :---: | :---: | :---: |
| $\wedge$ | caret | Legal anywhere | Included only | included only (avoid usage) | "To the power of", i.e., $2^{\wedge} 5$, two raised to the fifth power |
| \& | ampersand | Legal anywhere | Included only | Included only | n/a |
| * | asterisk | Included only (avoid using in node names) | Included only | included only (avoid using in parameter names) | Comment and wildcard character. Double asterisk (**) is "to the power of". |
| () | parentheses | Illegal | Illegal | Illegal | Token delimiter |
| - | minus | Included only | Included only | Illegal | n/a |
| - | underscore | Legal anywhere | Included only | Included only | n/a |
| + | plus sign | Included only | Included only | Included only (avoid usage) | Continues previous line, except for quoted strings |
| $=$ | equals | Illegal | Illegal | optional in <br> .PARAM <br> statements | Token delimiter |
| < > | less/more than | Legal anywhere | Included only | Included only | n/a |


| ? | question mark | Legal anywhere | Included only | Included only | Wildcard character |
| :---: | :---: | :---: | :---: | :---: | :---: |
| I | forward slash | Legal anywhere | Included only | Illegal | $\mathrm{n} / \mathrm{a}$ |
| \{ \} | curly braces | included only, converts to [] | Included only | Included only | Engine shall auto-convert to square brackets ([]) |
| [] | square brackets | Included only | Included only | Included only | n/a |
| 1 | backslash (requires a whitespace before to use as a continuation) | Included only | Included only | Illegal | Continuation character (preserves whitespace) |
| II | double backslash | Included only | Illegal | Illegal | Continuation character for quoted strings (preserves whitespace) |
| 1 | pipe | Legal anywhere | Included only | Included only | n/a |
| , | comma | Illegal | Illegal | Illegal | Token delimiter |
| - | period | Illegal | Included only | Included only | Statement identifier, (i.e., .PARAMETER, etc.). |
| : | colon | Included only | Included only | Included only | Delimiter for element attributes |


| $;$ | semi-colon | Included only | Included only | Included only | n/a |
| :--- | :--- | :--- | :--- | :--- | :--- |
| " " | double-quotes | Illegal | Illegal | Illegal | Expression and <br> filename <br> delimiter |
| ،, | single quotes | Illegal | Illegal | Illegal | Expression and <br> filename <br> delimiter |
|  | Blank <br> (whitespace) | Use before । <br> line (token) <br> continuations | Illegal | Illegal | Token delimiter |

*"Legal anywhere"=first character or any position in string
"Included only"=any position except first character
** cannot be the first character; element key letter only

## 4. First Character

The first character in every line specifies how IBIS-ISS interprets the remainder of the line.

## Table 3: First Character Rules

| If the First Character is... | Indicates |
| :--- | :--- |
| . (period) | Statement identifier (e.g., <br> .PARAM) |
| C, C, e, E, f, F, g, G, h, H, , <br> k, K, l, L, , , R, s, S, v, <br> V, w, W | Element instantiation |
| * (asterisk) | Comment line |
| + (plus) | Continues previous line |

## 5. Delimiters

Delimiters separate tokens (strings) in the input file. Input token delimiters are: tab, blank, comma (,), equal sign ( $=$ ), and parentheses ( ).

In addition, single (') or double quotes (") delimit tokens used as expressions and filenames.

## 6. Instance Names

The names of element instances begin with the element key letter, except for subcircuit instances, whose instance names begin with X. Instance names may be up to 1024 characters long.
Table 4 Element Identifiers

| Key Letter (First Char) | Element | Example Line |
| :---: | :---: | :---: |
| C | Capacitor | Cbypass 10 10pf |
| E | Voltage-controlled voltage source | Ea 1234 K |
| F | Current-controlled current source | Fsub n1 n2 vin 2.0 |
| G | Voltage-controlled current source | G12 4003010 |
| H | Current-controlled voltage source | H3 45 Vout 2.0 |
| K | Linear mutual inductor (general form) | K1 L1 L2 1 |
| L | Linear inductor | LX a b le-9 |
| R | Resistor | R10 21101000 |
| S | S-parameter element | S1 nd1 nd2 s_model2 |
| V | Voltage source | V1 80 DC=0 |


| W | Transmission Line | W1 in1 0 out1 $0 \mathrm{~N}=1 \mathrm{~L}=1$ |
| :---: | :---: | :---: |
| T | Transmission Line | $\begin{aligned} & \text { Txxx in } 0 \text { out } 0 \mathrm{Z} 0=50 \\ & \mathrm{TD}=30 \mathrm{n} \end{aligned}$ |
| X | Subcircuit instance | $\begin{array}{lllllll} \mathrm{X} 1 & 2 & 4 & 17 & 31 \\ \mathrm{LN}=5 \end{array}$ |

## 7. Numbers

Numbers may be entered as integer, floating point, floating point with an integer exponent, or integer or floating point with one of the scale factors listed below.

Table 5: Scale Factors

| Scale Factor | Prefix | Symbol | Multiplying Factor |
| :--- | :--- | :--- | :--- |
| T | tera | T | $1 \mathrm{e}+12$ |
| G | giga | G | $1 \mathrm{e}+9$ |
| MEG or $X$ | mega | M | $1 \mathrm{e}+6$ |
| K | kilo | k | $1 \mathrm{e}+3$ |
| MIL | n/a | none | $25.4 \mathrm{e}-6$ |
| M | milli | m | $1 \mathrm{e}-3$ |
| U | nano | n | $1 \mathrm{e}-9$ |
| N | pico | p | $1 e-12$ |
| P |  |  | $1 e-6$ |


| F | femto | $f$ | $1 e-15$ |
| :--- | :--- | :--- | :--- |
| A | atto | a | $1 \mathrm{e}-18$ |

## Note:

Scale factor A is not a scale factor in a character string that contains amps. For example, IBIS-ISS interprets the 20amps string as 20e-18mps ( $20^{-18} \mathrm{amps}$ ), but it correctly interprets 20amps as 20 amperes of current, not as $20 \mathrm{e}-18 \mathrm{mps}\left(20^{-18} \mathrm{amps}\right)$.

- Numbers may use exponential format or engineering key letter format, but not both (1e-12 or 1p, but not 1e-6u).
- To designate exponents, use D or E.
- Trailing alphabetic characters are interpreted as units comments.
- Units comments are not checked.


## 8. Parameters and Expressions

- Parameter names shall begin with an alphabetic character. Subsequent characters in the parameter name shall each be either a digit, or one of these following characters:

```
! # $ % [ ]
```

- If multiple definitions are given for the same parameter, IBIS-ISS uses the last parameter definition even if that definition occurs later in the input than a reference to the parameter.
- A parameter shall be defined before that parameter is used in a definition for another parameter.

To delimit expressions, single quotes shall be used
Expressions cannot exceed 1024 characters.

- Parameters are used in two contexts.
- Parameters in parameter definition statements are strings, defining names to be used as variables which are assigned specific values by the statement. These values may be numeric, strings defining an expression or equation, or strings matching parameters defined elsewhere.
- Parameters may also appear in element instances, model definitions and subcircuit definitions. These parameters may be user-defined or may use names pre-defined by the syntax of the element.
- Parameter names are input tokens. Token delimiters shall precede and follow names.
- Parameter names may be up to 1024 characters long and are not case-sensitive.


## 9. Node Name (or Node Identifier) Conventions

Nodes are the points of connection between elements in the input netlist. Only alphanumeric strings shall be used to designate nodes. If entirely numeric, node numbers shall be between 1 and 999999999999999 (1 to 1e16-1). A node number of 0 is permitted but is interpreted as ground. Letters that follow a leading number in a node name are ignored; this means that node strings such as '3n5' and ' 3 ' shall be interpreted as referring to the same node.

When the node name begins with a letter or a valid special character, the node name may contain a maximum of 1024 characters.

To indicate the ground node, use either the number 0 , the name GND, or ! GND, or GROUND, GND!. Every node shall have at least two connections, except for transmission line nodes (unterminated transmission lines are permitted) and MOSFET substrate nodes (which have two internal connections).

## 10. Element, Instance, and Subcircuit Naming Conventions

 Instances and subcircuits are elements and as such, follow the naming conventions for elements.Element names begin with a letter designating the element type, followed by up to 1023 alphanumeric characters. Element type letters are R for resistor, C for capacitor and so on.

## 11. Line Continuations

Lines are continued in one of three ways, depending on how input is divided across the line:

- Statements are continued using the + character
- Tokens are continued using the $\ 1$ sequence
- Tokens may also be continued using whitespace followed by the $\backslash$ character

To continue a statement across multiple lines, the plus (+) sign shall be used as the first non-numeric, non-blank character of each continued line. The + sign shall be used only between tokens and token delimiters and never to split tokens.

Here is an example of comments and line continuation in a netlist file:

```
*This shows continuation of a statement describing a resistor
Rexample
+ n3 n4 R=30
```

To continue a token with extended length (such as paths and expressions) but preserve readability, the token shall be split using a single whitespace character followed by a backslash ( $\backslash$ ) or a double backslash ( $\backslash 1$ ) without leading whitespace at the end of the line containing the token to be continued on the following line.

* This shows continuation of a token in a statement, in this
* case an expression, describing a resistor

Rexample n3 n4 R='sin(30.12345 + 4.356789- $\cos (32.67-\backslash \backslash$ 234) )'

* This shows an identical continuation of a token in a * statement, in this case an expression, describing a resistor Rexample n3 n4 R='sin(30.12345 + 4.356789 - $\cos (32.67-$ \} 234) '


## 6.Parameters

Parameters are similar to the variables used in most programming languages. Parameters hold values assigned when the circuit design is created or that are calculated based on circuit solution values. Parameters may store static values for a variety of quantities (resistance, source voltage, rise time, and so on). Parameters may also be alphabetic strings used with elements where string input is expected (for example, filenames or model names).

## Using Parameters in Simulation (.PARAM)

## Defining Parameters

Parameters may be defined using the methods shown below. Note that a .param statement without an assignment is not permitted.
Table 6: .PARAM Statement Syntax and Examples

| Token | Description/Example |
| :---: | :---: |
| Simple Assignment | . PARAM SimpleParam=1e-12 |
| Algebraic Definition | .PARAM AlgebraicParam='SimpleParam*8.2' |
| User-defined Function | . PARAM MyFunc $(x, y)={ }^{\text {a }} \operatorname{SQRT}\left(\left(x^{*} x\right)+\left(y^{*} y\right)\right)^{\prime}$ |
| String Assignment | . PARAM StringParam=str('mystring') |
| Subcircuit Definition | .SUBCKT SubName ParamDefName=Value |
| Subcircuit Instance | Xxxx nodename1 ... nodenamen <br> + SubName <br> + ParamDefName = Value \| str('string') |
| Predefined Analysis | $\begin{aligned} & \text {. PARAM } f(a, b)=\operatorname{POW}(a, 2)+a * b g(d)=\operatorname{SQRT}(d) \\ & +h(e)=e * f(1,2)-g(3) \end{aligned}$ |

A parameter definition in IBIS-ISS always uses the last value found in the input netlist. The definitions below assign a value of 3 to the DupParam parameter.

```
.PARAM DupParam=1
.PARAM DupParam=3
```

IBIS-ISS assigns 3 as the value for all instances of DupParam, including instances that are earlier in the input than the . PARAM DupParam=3 statement.

All parameter values in IBIS-ISS are IEEE double floating point numbers. The parameter resolution order is:

1. Resolve all literal assignments.
2. Resolve all expressions.
3. Resolve all function calls.

Table 7 shows the parameter passing order.

Table 7: Parameter Passing Order

| .PARAM statement () | .SUBCKT call (instance) |
| :--- | :--- |
| . SUBCKT call (instance) | .SUBCKT definition (symbol) |
| . SUBCKT definition (symbol) | .PARAM statement () |

## Assigning Parameters

The following types of values may be assigned to parameters:

- Constant real number
- Algebraic expression of real values
- Predefined function
- Circuit value
- Model value
- Strings not for algebraic evaluation

To invoke the algebraic processor, the complex expression to be evaluated shall be enclosed in single quotes.

A simple expression consists of one parameter name Simple expressions shall not be enclosed in single or double quotes.
The parameter keeps the assigned value, unless a later definition changes its value.

## Inline Parameter Assignments

To define circuit values, using a direct algebraic evaluation:
r1 n1 0 R='1k/sqrt(HERTZ)' \$ Resistance for frequency

## Using Algebraic Expressions

In IBIS-ISS, an algebraic expression, with quoted strings, may replace any parameter.

Some uses of algebraic expressions are:

- Parameters:
. PARAM $\mathrm{x}={ }^{\prime} \mathrm{y}+3^{\prime}$
- Algebra in elements:

R1 $10 \quad r=\prime \operatorname{ABS}(v(1) / i(m 1))+10^{\prime}$

The continuation character for quoted parameter strings, in IBIS-ISS, is a double backslash $(\backslash \backslash)$ (outside of quoted strings, the single backslash $(\backslash)$ is the continuation character).

## Built-In Functions and Variables

In addition to simple arithmetic operations (+, -, *, /), the built-in functions and variables listed below may be used in IBIS-ISS expressions.

Table 8: IBIS-ISS Built-in Functions

| IBIS-ISS Form | Function | Class | Description |
| :---: | :---: | :---: | :---: |
| $\sin (x)$ | sine | trig | Returns the sine of $x$ (radians) |
| $\cos (\mathrm{x})$ | cosine | trig | Returns the cosine of $x$ (radians) |
| $\tan (\mathrm{x})$ | tangent | trig | Returns the tangent of $x$ (radians) |
| $\operatorname{asin}(\mathrm{x})$ | arc sine | trig | Returns the inverse sine of $x$ (radians) |
| $\operatorname{acos}(\mathrm{x})$ | arc cosine | trig | Returns the inverse cosine of $x$ (radians) |
| $\operatorname{atan}(\mathrm{x})$ | arc tangent | trig | Returns the inverse tangent of $x$ (radians) |
| $\sinh (\mathrm{x})$ | hyperbolic sine | trig | Returns the hyperbolic sine of $x$ (radians) |
| $\cosh (\mathrm{x})$ | hyperbolic cosine | trig | Returns the hyperbolic cosine of $x$ (radians) |
| $\tanh (\mathrm{x})$ | hyperbolic tangent | trig | Returns the hyperbolic tangent of $x$ (radians) |
| abs(x) | absolute value | math | Returns the absolute value of $\mathrm{x}:\|\mathrm{x}\|$ |
| sqrt(x) | square root | math | Returns the square root of the absolute value of $x$ : $\operatorname{sqrt}(-x)=-\operatorname{sqrt}(\|x\|)$ |
| pow(x,y) | absolute power | math | Returns the value of $x$ raised to the integer part of $y$ : $x^{\text {(integer part of } y)}$ |


| pwr ( $\mathrm{x}, \mathrm{y}$ ) | signed power | math | Returns the absolute value of $x$, raised to the $y$ power, with the sign of $x$ : $(\operatorname{sign}$ of $x)\|x\|^{y}$ |
| :---: | :---: | :---: | :---: |
| $x^{\star *} y$ | power |  | If $x<0$, returns the value of $x$ raised to the integer part of $y$. <br> If $x=0$, returns 0 . <br> If $x>0$, returns the value of $x$ raised to the $y$ power. |
| $\log (\mathrm{x})$ | natural logarithm | math | Returns the natural logarithm of the absolute value of $x$, with the sign of $x$ : (sign of x) $\log (\|x\|)$ |
| $\log 10(\mathrm{x})$ | base 10 logarithm | math | Returns the base 10 logarithm of the absolute value of x , with the sign of x : (sign of $x) \log _{10}(\|x\|)$ |
| $\exp (\mathrm{x})$ | exponential | math | Returns e, raised to the power x : $\mathrm{e}^{\mathrm{x}}$ |
| $\mathrm{db}(\mathrm{x})$ | decibels | math | Returns the base 10 logarithm of the absolute value of $x$, multiplied by 20 , with the sign of $x$ : (sign of $x) 20 \log _{10}(\|x\|)$ |
| int(x) | integer | math | Returns the integer portion of $x$. The fractional portion of the number is lost. |
| nint(x) | integer | math | Rounds x up or down, to the nearest integer. |
| $\operatorname{sgn}(\mathrm{x})$ | return sign | math | Returns -1 if x is less than 0 . Returns 0 if $x$ is equal to 0 . <br> Returns 1 if $x$ is greater than 0 |
| $\operatorname{sign}(\mathrm{x}, \mathrm{y})$ | transfer sign | math | Returns the absolute value of $x$, with the sign of $y$ : (sign of $y)\|x\|$ |


| def(x) | parameter defined | control | Returns 1 if parameter $x$ is defined. <br> Returns 0 if parameter $x$ is not defined. |
| :---: | :---: | :---: | :---: |
| $\min (x, y)$ | smaller of two args | control | Returns the numeric minimum of $x$ and $y$ |
| $\max (\mathrm{x}, \mathrm{y})$ | larger of two args | control | Returns the numeric maximum of $x$ and $y$ |
| [cond] ? x : y | ternary operator |  | Returns $x$ if cond is not zero. Otherwise, returns $y$. <br> .param z='condition ? x:y' |
| < | relational operator (less than) |  | Returns 1 if the left operand is less than the right operand. Otherwise, returns 0 . .para $x=y<z$ ( $y$ less than $z$ ) |
| <= | relational operator (less than or equal) |  | Returns 1 if the left operand is less than or equal to the right operand. Otherwise, returns 0 . <br> .para $x=y<=z$ ( $y$ less than or equal to $z$ ) |
| > | relational operator (greater than) |  | Returns 1 if the left operand is greater than the right operand. Otherwise, returns 0 . <br> .para $x=y>z$ ( $y$ greater than $z$ ) |
| >= | relational operator (greater than or equal) |  | Returns 1 if the left operand is greater than or equal to the right operand. Otherwise, returns 0 . <br> .para $x=y>=z$ ( $y$ greater than or equal to $z$ ) |
| == | equality |  | Returns 1 if the operands are equal. Otherwise, returns 0. .para $x=y==z$ ( $y$ equal to $z$ ) |


| $!=$ | inequality |  | Returns 1 if the operands are not equal. <br> Otherwise, returns 0. <br> .para $x=y!=z ~(y ~ n o t ~ e q u a l ~ t o ~ z) ~$ |
| :--- | :--- | :--- | :--- |$|$| \&\& | Logical <br> AND |
| :--- | :--- |
| Otherwise, returns 0. .para $x=y \& \& z$ (y AND |  |
| z) |  |

Table 12 IBIS-ISS Special Variables

| IBIS-ISS Form | Function | Class | Description |
| :--- | :--- | :--- | :--- |
| time | current simulation <br> time | control | Uses parameters to define the current <br> simulation time, during transient analysis. |
| temper | current circuit <br> temperature | control | Uses parameters to define the current <br> simulation temperature, during <br> transient/temperature analysis. |
| hertz | current simulation <br> frequency | control | Uses parameters to define the frequency, <br> during AC analysis. |

## String Parameters

Parameters may be defined and instantiated using strings, String parameters use special syntax as tokens such as single quotes ('), double quotes ("), or curly brackets ( $\}$ ) do not work for string parameter definitions or usage.

When defining a parameter that is a character string, the token and delimiter combination str('string') shall be used to define the parameter, where string is be the string to be used as the parameter value. When an instance of the parameter is used, the parameter name is called as str(parameter_name).

IBIS-ISS supports string parameter definition and instantiation for the following netlist components:

- . PARAM statements
- . SUBCKT statements
- S-parameter FQMODEL in both the S-parameter instance and S-parameter model and the TSTONEFILE keyword in the S-element
- FILE and MODEL keywords
- W-element keywords RLGCFILE, RLGCMODEL, UMODEL, FSMODEL, TABLEMODEL, and SMODEL

String parameters may be used as arguments to all model name tokens.

## Syntax

```
Rxxx n1 n2 [mname [str(mname)]] Rval [TC1 [TC2][TC]] [SCALE=val]
+ [M=val] [AC=val] [DTEMP=val] [L=val] [W=val] [C=val]
+[NOISE = val]
```


## Parameter Scoping and Passing

If parameters are used to define values in sub-circuits, fewer similar cells should be used, to provide enough functionality in the resulting library. Circuit parameters may be passed into hierarchical designs, and different values may be assigned to the same parameter within individual cells, when simulations are run.

A parameter is defined either by a .parameter statement (local to that subcircuit), or may be passed into a subcircuit, or may be defined on a .subckt definition line.

```
.param x=0
```

. subckt def
.param x=1
x1 12 abc $x=2$
. subckt abc $12 \mathrm{x}=3$
.param x=3
r1 12 R=x
.ends abc
.ends def
.end

## 7.File Includes

The include statement inserts another file's contents in the current file at evaluation.

## Syntax

```
.INCLUDE 'file_path file_name'
.inc 'file_path file_name'
Arguments
```

Argument Description
file_path Path name of a file for computer operating systems that support treestructured directories.
An include file can contain nested .INCLUDE calls to itself or to another include file. If a relative path is used in a nested .INCLUDE call, the path starts from the directory of the parent .INCLUDE file, not from the current working directory. If the path starts from the current working directory, IBIS-ISS may also find the .INCLUDE file, but prints a warning.
file_name Name of a file to include in the data file. The file path, plus the file name, may be up to 16 characters long. Any name valid under the computer's operating system may be used.

Use this token to include another netlist in the current circuit description. The file path and file name shall be enclosed in single or double quotation marks.

## 8. Comments

Comments require an asterisk (*) as the first character in a line or a dollar sign (\$) directly in front of the comment anywhere on the line. For example:

* <comment_on_a_line_by_itself>
or
<IBIS-ISS statement> \$ <comment following input>
Comment statements may appear anywhere in the circuit description. The dollar sign $(\$)$ shall be used for comments that do not begin in the first character position on a line (for example, for comments that follow simulator input on the same line). If it is not the first nonblank character, then the dollar sign shall be preceded by either:
- Whitespace
- Comma (,)
- Valid numeric expression

The dollar sign may also be used within node or element names. For example:

```
* RF=1K GAIN SHOULD BE 100
$ CIRCUIT EXAMPLE
VIN 1 0 PL 0 0 5V 5NS $ 10v 50ns
R12 1 0 1MEG $ FEED BACK
.PARAM a=1w$comment a=1, w treated as a space and ignored
.PARAM a=1k$comment a=1e3, k is a scale factor
```

A dollar sign is the preferred way to indicate comments, because of the flexibility of its placement within the code.

## 9.Model Definitions (.MODEL Statements)

Model definitions are used to specify the electrical parameters for $W$-element and S-element instances. They can be considered a special form of subcircuit definition, in which the defined subcircuit is only available to W - and Selements.

The specific syntax for $W$-element and S-element .MODEL definitions are detailed below, as part of the W-element and S-element portions of the IBISISS specification. Note that .MODEL statements are hierarchically at the same level as element instances.

## 10. Subcircuit Definitions

Syntax<br>. subckt name n1 n2...<br>statement<br>statement<br>statement<br>...<br>.ends

## 1. Subcircuit Scoping Rules

A .subckt or .model definition shall occur in the subcircuit in which the subcircuit or model is referenced, or in a calling subcircuit at any level above.

## 11. Subcircuit Definition Ending Statements

Subcircuit definitions shall end with the .ends token. See Subcircuit Definitions above for syntax and examples.

## 12. Elements

The sections below describe the individual circuit elements that may appear in an IBIS-ISS file.

## 1. Subcircuits

Reusable cells are the key to saving labor in any CAD system. To create and simulate a reusable circuit, construct it as a subcircuit.Use parameters to expand the utility of a subcircuit.
x<subcircuit_name> creates an instance of a subcircuit. . The subcircuit shall have already been defined elsewhere in the IBIS-ISS file using a . SUBCKT statement.

Syntax
Xxxxx n1 [ $n 2$ n3 ...] subnam
$[$ parnam $=$ val] $[M=$ val]

| Argument | Definition |
| :--- | :--- |
| X<subcircuit_name> | Subcircuit element name. Shall begin with an X, <br> followed by up to 15 alphanumeric characters. |
| $n 1 \ldots$ | Node names for external reference. |
| subnam | Subcircuit model reference name. |
| Parnam parameter name set to a value (val) for use only in |  |
| the subcircuit. It overrides a parameter value in the |  |
| subcircuit definition, but is overridden by a value set in |  |
| a . PARAM statement. |  |

## 2. Linear Resistor

A linear resistor is a basic electrical circuit element for impeding current flow.

## Syntax

Rxxx nodel node2 [ $\mathrm{R}=$ ] value
The value of a linear resistor may be a constant, or an expression of parameters.

| Token | Description |
| :--- | :--- |
| Rxxx | Name of a resistor |
| node1 and node2 | Names or numbers of the connecting nodes |
| value | resistance value, in ohms |

## 3. Linear Capacitor

A linear capacitor is a basic electrical circuit element for charge storage.

## Syntax

Cxxx nodel node2 [C=] value
The value of a linear capacitor may be a constant, or an expression of parameters.

## Token Description

Cxxx Name of a capacitor. Shall begin with C, followed by up to 1023 alphanumeric characters.
node1, node2 Names of connecting nodes.
value
Capacitance value, in farads.

## 4. Voltage Shunt

A voltage shunt creates a short between two nodes.

## Syntax

Vxxx node1 node2 [DC=]0

## Token Description

Vxxx Voltage shunt element name. Shall begin with K, followed by up to 1023 alphanumeric characters.
node1, node $2 \quad$ Nodes between which the shunt is placed.
$D C=0 \quad$ The zero value is required and sets the voltage between the nodes at zero volts. The text "DC=" is optional.

## 5. Mutual Inductor

A mutual inductor describes inductive coupling between two defined inductors.

## Syntax

Kxxx Lyyy Lzzz [K=]coupling

## Token Description

| Kxxx | Mutual inductor element name. Shall begin with K, followed by <br> up to 1023 alphanumeric characters. |
| :--- | :--- |
| Lyyy | Name of the first of two coupled inductors. This inductor shall <br> be defined elsewhere in the file. |
| Lzzz $\quad$Name of the second of two coupled inductors. This inductor <br> shall be defined elsewhere in the file. |  |
| Coefficient of mutual coupling. This is a unitless number, with |  |
| magnitude > 0. If the coupling coefficient is negative, the <br> direction of coupling reverses. This is equivalent to reversing <br> the polarity of either of the coupled inductors. Use the K=xxx <br> syntax when defining the coupling coefficient using a parameter <br> name or an equation. The pre-defined parameter " $k$ " may be |  |

omitted.

## 6. Linear Inductor

## Syntax

Lxxx node1 node2 [L =] inductance

| Token | Description |
| :--- | :--- |
| Lxxx | Name of an inductor. |
| node1,node2 | Names or numbers of the connecting nodes. |
| inductance | inductance value, in henries. |

## 7. T-element (Ideal Transmission Line)

Syntax
Txxx in refin out refout Z0=val TD=val [L=val]
$+[I C=v 1, ~ i 1, ~ v 2, ~ i 2]$

Token Description

Txxx Lossless transmission line element name. Shall begin with T , followed by up to 1023 alphanumeric characters.

In
Signal input node.

Refin Ground reference for the input signal.

Out Signal output node.

Refout Ground reference for the output signal.

Characteristic impedance of the transmission line (Ohms).

TD Propagation time delay of the transmission line (in seconds). If physical length (L) is specified, then units for TD are considered in seconds per meter.

L
Physical length of the transmission line, in units of meters. Default=1.

## 8. W-element (Coupled Transmission Line)

This section describes how to use basic transmission line simulation equations and an optional method for computing the parameters of transmission line equations.

The W-element is a versatile transmission line model that may be used to describe a variety of transmission line structures, from a simple lossless line to complex frequency-dependent lossy-coupled lines.

## Syntax

```
Wxxx il i2 ... iN iR ol o2 ... oN or N=val L=val
```

+ [RLGCMODEL=name | TABLEMODEL=name]
Token Description
$N \quad$ Number of signal conductors (excluding the reference conductor).
i1...iN Node names for the near-end signal-conductor terminal
iR Node name for the near-end reference-conductor terminal.
o1... oN Node names for the far-end signal-conductor terminal
oR Node name for the far-end reference-conductor terminal.
$\mathrm{L} \quad$ Length of the transmission line.

RLGCMODEL Name of the RLGC model.

TABLEMODEL Name of the frequency-dependent tabular model

The W-element supports two formats to specify transmission line properties:

- Format 1: RLGC specification
- Internally specified in a . MODEL statement.
- Externally specified in a different file.
- Format 2: Frequency-dependent tabular specification

Parameters in the W-element element declaration may be declared in any order. Specify the number of signal conductors, N , after the list of nodes. The nodes and parameters in the W-element element declaration may be interspersed.

## Format 1: RLGC Model

The inputs of the W -element are given in per unit length matrices: $\mathrm{R}_{0}$ (DC resistance), $L, G, C, R_{S}$ (skin effect), and $G_{d}$ (dielectric loss)
The W-element does not limit any of the following parameters:

- Number of coupled conductors.
- Shape of the matrices.
- Line loss.
- Length or amount of frequency dependence.

The RLGC text file contains frequency-dependent RLGC matrices per unit length. The W-element also handles frequency-independent RLGC, and lossless (LC) lines. It does not support RC lines.
Because RLGC matrices are symmetrical, the RLGC model specifies only the lower triangular parts of the matrices. The syntax of the RLGC model for the W-element is:

```
.MODEL name W MODELTYPE=RLGC N=val
+ Lo=matrix_entries
+ Co=matrix_entries [Ro=matrix_entries Go=matrix_entries]
+ Rs=matrix_entries wp=val Gd=matrix_entries Rogñd=val
+ Rsgnd=val Lgnd=val
```


## Token Description

N Number of conductors (same as in the element card).

L
DC inductance matrix, per unit length $\left[\frac{\mathrm{H}}{\mathrm{m}}\right]$.

C
DC capacitance matrix, per unit length $\left[\frac{F}{m}\right]$.

Ro
DC resistance matrix, per unit length $\left[\frac{\Omega}{m}\right]$.

Go
DC shunt conductance matrix, per unit length $\left[\frac{S}{m}\right]$.

Rs
Skin effect resistance matrix, per unit length $\left[\frac{\Omega}{\mathrm{m} \sqrt{\mathrm{Hz}}}\right]$.

Gd
Dielectric loss conductance matrix, per unit length $\left[\frac{\mathrm{S}}{\mathrm{m} \cdot \mathrm{Hz}}\right]$.
wp Angular frequency of the polarization constant [radian/sec] (see Introduction to the Complex Dielectric Loss Model). When the wp value is specified, the unit of Gd becomes [ $\mathrm{S} / \mathrm{m}$ ].

Lgnd
DC inductance value, per unit length for grounds ${ }^{\left[\frac{H}{m}\right]}$ (reference line).

Rognd
DC resistance value, per unit length for ground $\left[\frac{\Omega}{m}\right]$.

Rsgnd
Skin effect resistance value, per unit length for ground $\left[\frac{\Omega}{m \sqrt{\mathrm{~Hz}}}\right]$.

The following input netlist file shows RLGC input for the W-element:

* W-Element example, four-conductor line

```
W1 N=3 1 3 5 0 2 4 6 0 RLGCMODEL=example_rlc l=0.97
* RLGC matrices for a four-conductor lossy
.MODEL example_rlc W MODELTYPE=RLGC N=3
+ LO=
+ 2.311e-6
+ 4.14e-7 2.988e-6
+ 8.42e-8 5.27e-7 2.813e-6
+ CO=
+ 2.392e-11
+ -5.41e-12 2.123e-11
+ -1.08e-12 -5.72e-12 2.447e-11
+ RO=
+ 42.5
+ 041.0 + 0 0 33.5
+GO= + 0.000609
+ -0.0001419 0.000599
+ -0.00002323-0.00009 0.000502
+ Rs=
+ 0.00135
+ 00.001303
+ 000.001064
+ Gd=
+ 5.242e-13
+ -1.221e-13 5.164e-13
+ -1.999e-14 -7.747e-14 4.321e-13
```


## Using RLGC Matrices

RLGC matrices in the RLGC model of the W-element are in the Maxwellian format

## Format 2: Frequency-Dependent Tabular Specification

The tabular RLGC model may be used as an extension of the analytical RLGC model to model any arbitrary frequency-dependent behavior of transmission lines (this model does not support RC lines).

The W-element syntax supports tables of data (use a .MODEL statement of type w). To accomplish this, the . MODEL statement refers to .MODEL statements where the "type" is SP (described in Small-Signal Parameter Data Frequency Table Model (SP Model)), which contain the actual table data for the RLGC matrices.

## Note:

To ensure accuracy, the W-element tabular model requires the following:

- R and G tables require zero frequency points.
- L and C tables require infinity frequency points as well as zero frequency points.
To specify a zero frequency point, the pre-defined DC parameter may be used. Alternatively, the $f$ parameter in the DATA field of the SP model may be set to a value of 0 . To specify an infinity frequency point, use the INFINITY token.

See also, Small-Signal Parameter Data Frequency Table Model (SP Model).

## Introduction to the Complex Dielectric Loss Model

When the INCLUDEGDIMAG token = yes and there is no wp input, the W-element regards the Gd matrix as the conventional model and then automatically extracts constants for the complex dielectric model.

In conventional use, the HSPICE W-element RLGC model, frequency-dependent conductance is approximated as Eq. 36 .

Where, Eq. 36 represents the increase of shunt conductance due to dielectric loss. These pure real non-constant functions of frequency violate causality [1]. As system operating frequency becomes significantly high even for PCB systems which use high polymer dielectric materials like FR4, the appearance of the dielectric loss becomes significant and significant non-causality of Eq. 36 appears.

## Frequency-Dependent Matrices

The frequency-dependent loss of the shunt conductance in the dielectric is mainly due to dielectric polarization. This polarization loss leads to a complex permittivity [xxx] for the dielectric material[2].

Equation 37
And loss tangent of the dielectric material can be specified as the ratio of imaginary part of to the real part,

## Equation 38

For a single dielectric dipolar moment, complex electric permittivity can be written as,

## Equation 39

Where, and are low and high frequency limits of dielectric permittivity which are real numbers. And is the angular frequency that corresponds to the polarization time constant of the dielectric material. From Eq. 39, frequency-dependent complex shunt loss conductance can be expressed as [3],

## Equation 40

Where, the imaginary part of the conductance contributes reactively. In cases of multiple dielectric materials surrounding the system, the complex loss conductance can be extended as linear combinations of multiple dipole moments as,

## Equation 41

Since Eq. 41 satisfies the Kramers-Kronig condition, we can ensure the passivity/causality of the system. Note that when this new model is activated, the definition of Gd changes from conventional $\left[\mathrm{S} / \mathrm{m}^{*} \mathrm{~Hz}\right]$ to $[\mathrm{S} / \mathrm{m}]$.

## Small-Signal Parameter Data Frequency Table Model (SP Model)

The small-signal parameter data frequency table model (SP model) is a generic model that describes frequency-varying behavior.

## Syntax

```
.MODEL name sp [N=val FSTART=val FSTOP=val NI=val
+ SPACING=val MATRIX=val VALTYPE=val INFINITY=matrixval
+ INTERPOLATION=val EXTRAPOLATION=val] [DATA=(npts ...)]
+ [DATAFILE=filename]
```

Parameter Description

| Token | Description |
| :--- | :--- |
| N | Matrix dimension (number of signal terminals). Default is 1. If you <br> use a value other than the default, you must specify that value <br> before you set INFINITY and DATA |
| FSTART | Starting frequency point for data. Default=0. |
| FSTOP | Final frequency point for data. Use this parameter only for the <br> LINEAR and LOG spacing formats. |
| NI | Number of frequency points per interval. Use this parameter only for <br> the DEC and OCT spacing formats. Default=10. |

SPACING Data sample spacing format:

- LIN (LINEAR): uniform spacing with frequency step of (FSTOP-FSTART)/(npts-1). The default.
- OCT: octave variation with FSTART as the starting frequency and NI points per octave. npts sets the final frequency.
- DEC: decade variation with FSTART as the starting frequency and NI points per decade. npts sets the final frequency.
- LOG: logarithmic spacing. FSTART and FSTOP are the starting and final frequencies.
- POI: non-uniform spacing. Pairs data (NONUNIFORM) points with frequency points.

MATRIX Matrix (data point) format:

- SYMMETRIC: symmetric matrix. Specifies only lower-half triangle of a matrix (default).
- HERMITIAN: similar to SYMMETRIC; off-diagonal terms are complex conjugates of each other.
- NONSYMMETRIC: non-symmetric (full) matrix.

VALTYPE Data type of matrix elements:

- REAL: real entry.
- CARTESIAN: complex number in real/imaginary format (default)
- POLAR: complex number in polar format. Specify angles in radians.

INFINITY Data point at infinity. Typically real-valued. This data format must be consistent with MATRIX and VALTYPE specifications. Npts does not count this point.

INTERPOLA Interpolation scheme:

- STEP: piecewise step (default).
- LINEAR: piecewise linear.
- SPLINE: b-spline curve fit.

EXTRAPOL Extrapolation scheme during simulation:
ATION

- NONE: no extrapolation is allowed. Simulation terminates if a required data point is outside of the specified range.
- STEP: uses the last boundary point. The default.
- LINEAR: linear extrapolation by using the last two boundary points.

If the data point at infinity is specified, then extrapolation is not used.
npts $\quad$ Number of data points.

DC $\quad$ Data port at DC. Normally real-valued. This data format must be consistent with MATRIX and VALTYPE specifications. npts does not count this point. You must specify either the DC point or the data point at frequency=0.

DATA Data points.

- Syntax for LIN spacing:
.MODEL name sp SPACING=LIN [N=dim] FSTART=f0
+ DF=f1 DATA=npts d1 d2 ...
- Syntax for OCT or DEC spacing:
.MODEL name sp SPACING=DEC or OCT [ $\mathrm{N}=\mathrm{dim}$ ]
+ FSTART=f0 NI=n_per_intval DATA=npts d1 d2 ...
- Syntax for POI spacing:
.MODEL name sp SPACING=NONUNIFORM [N=dim] + DATA=npts f1 d1 f2 d2 ...

DATAFILE Data points in an external file. This file must contain only raw numbers without any suffixes, comments or continuation letters. The first number in the file must be an integer value to indicate the number of sampling points in the file. Then, sampling data must follow. The order of sampling data must be the same as in the DATA statement. This data file has no limitation on line length.

## W-element Model Definition Syntax

```
.MODEL name W MODELTYPE=TABLE [FITGC=0|1] N=val
+ LMODEL=l_freq_model CMODEL=c_freq_model
+ [RMODEL=r freq model GMODEL=g freq model]
```


## Token Description

| FITCG | Pre-defined parameter token for the W-element with |
| :--- | :--- |
| MODELTYPE=TABLE. A value of 1 instructs the tool to run a |  |
| causality check on the data. A value of 0 turns any causality checking |  |
| off (default) |  |

$\mathrm{N} \quad$ Number of signal conductors (excluding the reference conductor).

LMODEL SP model name for the inductance matrix array.

CMODEL SP model name for the capacitance matrix array.

RLMODEL SP model name for the resistance matrix array. By default, it is zero.

GMODEL SP model name for the conductance matrix array. By default, it is zero.

## 9. S-element

An S-element is a frequency-domain set of network data, described using scattering parameters.

## Syntax

Sxxx nd1 nd2 ... ndN [ndRef]

+ MNAME=Smodel_name
+ [FBASE = base_frequency] [FMAX=maximum_frequency]
Token Description
nd1 nd2...ndN Nodes of an S-element Three kinds of definitions are present:
- With no reference node ndRef, the default reference node is GND. Each node ndi ( $\mathrm{i}=1 \sim \mathrm{~N}$ ) and GND construct one of the N ports of the S-element.
- With one reference node, ndRef is defined. Each node ndi (i=1~N) and the ndRef construct one of the $N$ ports of the S-element.
- With an $N$ reference node, each port has its own reference node. The node definition may be written more clearly: nd1+ nd1- nd2+ nd2- ... ndN+ ndNEach pair of the nodes (ndi+ and ndi-, $\mathrm{i}=1 \sim \mathrm{~N}$ ) constructs one of the N ports of the S -element.
ndRef

MNAME

Reference node

Name of the S model; Note that string parameters are supported in calling an MNAME.

Base frequency to use for transient analysis. This value becomes the base frequency point for Inverse Fast Fourier Transformation (IFFT).

- If this value is not set, the base frequency is a reciprocal value of the transient period.
- If a frequency is set that is smaller than the reciprocal value of the transient, then transient analysis performs circular convolution, and uses the reciprocal value of FBASE as its base period.

FMAX
Maximum frequency use in transient analysis. Used as the maximum frequency point for Inverse Fast Fourier Transformation (IFFT).

The nodes of the S-element be placed immediately after the identifier token. All optional parameters in both the S-element and S model statements may be defined by the user, except for MNAME argument.

The optional arguments may be entered in any order, and the parameters specified in the element statement have a higher priority.


Figure 27 Terminal Node Notation

## Node Example

The following example illustrates the nd1 nd2...ndN-no reference, single reference, and multi-reference parameters.

```
**S-parameter example
```

* no reference
s_no_ref n1 n2 mname=s_model
* single reference
S_one_ref n1 n3 gnd mname=s_model
*multi-reference
s_multi_ref n1 gnd n4 gnd mname=s_model

The S-element must have a call to one of the supported S-parameter file formats (IBIS-ISS gets the number of ports from the S-parameter file The number of ports, ' n ', may be specified explicitly as $\mathrm{N}=\mathrm{n}$.

- For $n$ terminals, the S -element assumes no reference node.
- For $\mathrm{n}+1$ terminals, the S -element assumes one reference node.
- For 2 n terminals, the S -element assumes signal nodes and n reference nodes. Each pair of nodes is a signal and a reference node.


## S Model Syntax

Use the following syntax to describe specific S models:

```
.MODEL Smodel_name S [N=dimension]
+ [TSTONEFILE=filename
+ [FBASE=base_frequency] [FMAX=maximum_frequency]
```


## Token Description

Smodel_name $\quad$ Name of the S model.

S Specifies that the model type is an S model.

N S model dimension, which is equal to the terminal number of an S-element and excludes the reference node.

TSTONEFILE Specifies the name of a Touchstone file. Data contains frequencydependent array of matrixes. Touchstone files must follow the .s\#p file extension rule, where \# represents the dimension of the network. Note that string parameters are supported for TSTONEFILE Example:
.subckt sparam n1 n2 tsfile=str('ss_ts.s2p')
S1 n1 n2 0 mname=s_model .model s_model S TST̄ONEFILE=str(tsfile)
.ends
x1 A B sparam tsfile=str('ss_ts.s2p')
For details, see Touchstone ${ }^{\circledR}$ File Format Specification by the IBIS Open Forum (http://www.eda.org/ibis/).

FBASE Base frequency used for transient analysis. IBIS-ISS uses this value as the base frequency point for Fast Inverse Fourier Transformation (IFFT).

- If FBASE is not set, IBIS-ISS uses a reciprocal of the transient period as the base frequency.
- If FBASE is set smaller than the reciprocal value of transient period, transient analysis performs circular convolution by using the reciprocal value of FBASE as a base period.

FMAX Maximum frequency for transient analysis. Used as the maximum frequency point for Inverse Fast Fourier Transform (IFFT).

The, TSTONEFILE parameters describe the frequency-varying behavior of a network.

## 10. E-element (Voltage-Controlled Voltage Source)

This section explains the E-element syntax and parameters.

## Linear

```
Exxx n+ n- [VCVS] in+ in- gain
```

For a description of these parameters, see table VCVS Parameters.

## Laplace Transform

Voltage Gain H(s):

```
ExXx n+ n- LAPLACE in+ in- k0, kl, ..., kn / do,
    dI, ..., dm
```

For a description of these parameters, see table VCVS Parameters.
$H(s)$ is a rational function, with parameters used to define the values of all coefficients $\left(k_{0}, k_{1}, \ldots, d_{0}, d_{1}, \ldots\right)$.

## Pole-Zero Function

Voltage Gain H(s):
Exxx n+ n- POLE int in- a azl, fzi, ..., azn, fzn / b, + apl, fpl, ..., apm, fpm
For a description of these parameters, see table VCVS Parameters.
The following equation defines $\mathrm{H}(\mathrm{s})$ in terms of poles and zeros:
$H(s)=\frac{a \cdot\left(s+\alpha_{z 1}-j 2 \pi f_{z 1}\right) \ldots\left(s+\alpha_{z n}-j 2 \pi f_{z n}\right)\left(s+\alpha_{z n}+j 2 \pi f_{z n}\right)}{b \cdot\left(s+\alpha_{p 1}-j 2 \pi f_{p 1}\right) \ldots\left(s+\alpha_{p m}-j 2 \pi f_{p m}\right)\left(s+\alpha_{p m}+j 2 \pi f_{p m}\right)}$
The complex poles or zeros are in conjugate pairs. The element description specifies only one of them, and the program includes the conjugate.
Parameters may be used to specify the $a, b, \alpha$, and $f$ values.

## Example

Elow_pass out 0 POLE in 0 1.0 / 1.0, 1.0,0.0 0.5,0.1379

The Elow_pass statement describes a low-pass filter, with the transfer function:

$$
H(s)=\frac{1.0}{1.0 \cdot(s+1)(s+0.5+j 2 \pi \cdot 0.1379)(s+0.5-(j 2 \pi \cdot 0.1379))}
$$

## Foster Pole-Residue Form

```
Gain \(\mathrm{E}(\mathrm{s})\) form
Exxx n+ n- FOSTER in+ in- k0 kl
\(+(\operatorname{Re}\{A 1\}, \operatorname{Im}\{A 1\}) /(\operatorname{Re}\{p 1\}, \operatorname{Im}\{p 1\})\)
\(+(\operatorname{Re}\{A 2\}, \operatorname{Im}\{A 2\}) /(\operatorname{Re}\{p 2\}, \operatorname{Im}\{p 2\})\)
\(+(\operatorname{Re}\{A 3\}, \operatorname{Im}\{A 3\}) /(\operatorname{Re}\{p 3\}, \operatorname{Im}\{p 3\})\)
+ . . .
```

For a description of these parameters, see Common Source Parameters.
In the above syntax, parentheses, commas, and slashes are separators-they have the same meaning as a space. A pole-residue pair is represented by four numbers (real and imaginary part of the residue, then real and imaginary part of the pole).

For convergence, the Re[pi] must be less than zero. For an N-port admittance matrix $\mathrm{Y}, \operatorname{Re}\{\mathrm{Y}\}$ should be positive-definite to ensure passivity of the model.

## Note:

For real poles, half the residue value is entered because it is applied twice. In the above example, the first pole-residue pair is real, but is written as "A1/(s-p1)+A1/(s-p1)"; therefore, 0.0004 is entered rather than 0.0008 .

## E-element Parameters

The E-element parameters are described in the following list.

| Token | Description |
| :--- | :--- |
| Exxx | Voltage-controlled element name. Must begin with E, followed <br> by up to 1023 alphanumeric characters. |
| in +/- | Voltage gain. <br> dimension. |
| K Ideal transformer turn ratio: V(in+,in-) $=k \cdot V(\mathrm{n}+, \mathrm{n}-)$ or, |  |
| number of gates input. |  |$\quad$| Positive or negative node of a controlled element. |
| :--- |

## 11. F-element (Current-Controlled Current Source)

This section explains the F-element syntax and parameters.
Note:
G-elements with algebraic expressions may be used to duplicate the functions of an F-element.

## Syntax

Fxxx n+ n- [CCCS] vn1 gain

## F-element Parameters

The F-element parameters are described in the following list.

| Token | Description |
| :--- | :--- |
| CCCS | Pre-defined token for current-controlled current source. CCCS is a <br> IBIS-ISS reserved word; do not use it as a node name. |
| gxxx | Element name of the current-controlled current source. Must begin <br> with F, followed by up to 1023 alphanumeric characters. |
| $\mathrm{n}+/-$ | Current gain. |
| $\mathrm{vn1} \ldots$ | Names of voltage sources, through which the controlling current <br> flows. Specify one name for each dimension. |
| $\mathrm{x} 1, \ldots$ | Controlling current, through the vn1 source. Specify the $x$ values in <br> increasing order. |
| $y 1, \ldots$ | Corresponding output current values of $x$. |

## 12. G-element (Voltage-Controlled Current Source)

This section explains G-element syntax statements, and their parameters.

## Linear

Gxxx n+ n- [VCCS] in+ in- transconductance
For a description of the G-element parameters, see Table VCCS Parameters.

## Laplace Transform

Transconductance $\mathrm{H}(\mathrm{s})$ :
GXXX $n+n-$ LAPLACE int in- $k 0, k 1, \ldots, k n / d o$,
$\quad d 1, \ldots m$
$\mathrm{H}(\mathrm{s})$ is a rational function, in the following form:
$H(s)=\frac{k_{0}+k_{1} s+\ldots+k_{n} s^{n}}{d_{0}+d_{1} s+\ldots+d_{m} s^{m}}$
Parameters may be used to define the values of all coefficients ( $\mathrm{k}_{0}, \mathrm{k}_{1}, \ldots, \mathrm{~d}_{0}$, $d_{1}, \ldots$.

## Pole-Zero Function

Transconductance H(s):
Gxxx n+ n- POLE in+ in- a az1, fz1, ..., azn, fzn / b, + ap1, fp1, ..., apm, fpm
The following equation defines $\mathrm{H}(\mathrm{s})$ in terms of poles and zeros:
$H(s)=\frac{a \cdot\left(s+\alpha_{z 1}-j 2 \pi f_{z 1}\right) \ldots\left(s+\alpha_{z n}-j 2 \pi f_{z n}\right)\left(s+\alpha_{z n}+j 2 \pi f_{z n}\right)}{b \cdot\left(s+\alpha_{p 1}-j 2 \pi f_{p 1}\right) \ldots\left(s+\alpha_{p m}-j 2 \pi f_{p m}\right)\left(s+\alpha_{p m}+j 2 \pi f_{p m}\right)}$
The complex poles or zeros are in conjugate pairs. The element description specifies only one of them, and the simulation program will include the conjugate automatically. Parameters may be used to specify the $\mathrm{a}, \mathrm{b}, \alpha$, and f values.
For a description of the G-element parameters, see Common Source Parameters.

## Example

Ghigh_pass 0 out POLE in 0 1.0 0.0,0.0 / 1.0 0.001,0.0

The Ghigh_pass statement describes a high-pass filter, with the transfer function:

$$
H(s)=\frac{1.0 \cdot(s+0.0+j \cdot 0.0)}{1.0 \cdot(s+0.001+j \cdot 0.0)}
$$

## Foster Pole-Residue Form

Transconductance G(s) form

```
Gxxx n+ n- FOSTER in+ in- k0 kl
+(Re{A1}, Im{A1})/ (Re{p1}, Im{p1})
+(Re{A2}, Im{A2})/ (Re{p2}, }\operatorname{Im}{\textrm{P}2}
+(Re{A3}, Im{A3})/ (Re{p3}, Im{p3})
+ ...
```

In the above syntax, parenthesis, commas, and slashes are separators-they have the same meaning as a space. A pole-residue pair is represented by four numbers (real and imaginary part of the residue, then real and imaginary part of the pole).

For convergence, the Re[pi] shall be less than zero. For an N-port admittance matrix $\mathrm{Y}, \operatorname{Re}\{\mathrm{Y}\}$ should be positive-definite to ensure passivity of the model.
For a description of the G-element parameters, see Common Source Parameters.

## Example

To represent a G(s) in the form,

$$
\begin{aligned}
& G(s)=0.001+1 \times 10^{-12} s+\frac{0.0008}{s+1 \times 10^{10}}+\frac{(0.001-j 0.006)}{s-\left(-1 \times 10^{8}+j 1.8 \times 10^{10}\right)}+ \\
& \frac{(0.001+j 0.006)}{s-\left(-1 \times 10^{8}-j 1.8 \times 10^{10}\right)}
\end{aligned}
$$

The IBIS-ISS syntax is:

$$
\begin{aligned}
& \text { G1 } 10 \text { FOSTER } 200.0011 \mathrm{e}-12 \\
& +(0.0004,0) /(-1 \mathrm{e} 10,0)(0.001,-0.006) /(-1 \mathrm{e} 8,1.8 \mathrm{e} 10)
\end{aligned}
$$

## Note:

For real poles, half the residue value is entered because it is applied twice. In the above example, the first pole-residue pair is real, but is
written as "A1/(s-p1)+A1/(s-p1)"; therefore, 0.0004 is entered rather than 0.0008 .

## G-element Parameters

The G-element parameters are described in the following list.

| Token | Description |
| :---: | :---: |
| Gxxx | Name of the voltage-controlled element. Must begin with G, followed by up to 1023 alphanumeric characters. |
| in +/- | Positive or negative controlling nodes. Specify one pair for each dimension. |
| n+/- | Positive or negative node of the controlled element. |
| transconductance | Voltage-to-current conversion factor. |
| vccs | Pre-defined token for the voltage-controlled current source. VCCS is a reserved IBIS-ISS word; do not use it as a node name. |
| x1,... | Controlling voltage, across the in+ and in- nodes. Specify the $x$ values in increasing order. |
| y1,... | Corresponding element values of $x$. |

## 13. H-element (Current-Controlled Voltage Source)

This section explains H-element syntax statements, and defines their parameters.
Note:
The E-element with algebraic expressions may be used to duplicate the function of the H -element.

## Syntax

Hxxx n+ n- [CCVS] vnl transresistance

| Token | Description |
| :--- | :--- |
| CCVS | Pre-defined token for the current-controlled voltage source. CCVS <br> is a IBIS-ISS reserved word; do not use it as a node name. |
| Hxxx | Element name of current-controlled voltage source. Must start <br> with H, followed by up to 1023 alphanumeric characters. |
| $\mathrm{n}+/-$ | Connecting nodes for positive or negative controlled source. |
| vnansresistance | Current-to-voltage conversion factor. |
| flows. One name for each dimension shall be specified. |  |

## 14. Common Source Parameters

Input parameters common to all sources are shown in the following list.

## Token Description

$$
\text { ABS } \quad \text { Output is an absolute value if } A B S=1 .
$$

DELAY Pre-defined token for the delay element, corresponding to propagation delay of the source. DELAY is a reserved word, which shall not be used as a node name.

| DELTA | Controls the curvature of the piecewise linear corners. This parameter defaults to one-fourth of the smallest distance between breakpoints. The maximum is one-half of the smallest distance between breakpoints. |
| :---: | :---: |
| Exxx | Voltage-controlled element name. Must begin with E, followed by up to 1023 alphanumeric characters. |
| gain | Voltage gain. |
| gatetype(k) | Can be AND, NAND, OR, or NOR. $k$ represents the number of inputs of the gate. $x$ and $y$ represent the piecewise linear variation of output, as a function of input. In multi-input gates, only one input determines the state of the output. |
| IC | Initial condition: initial estimate of controlling voltage value(s). If IC is not specified, the default=0.0. |
| in +/- | Positive or negative controlling nodes. Specify one pair for eachdimension. |
| k | Ideal transformer turn ratio: $\mathrm{V}(\mathrm{in}+$, in- $)=k \oplus \mathrm{~V}(\mathrm{n}+, \mathrm{n}-)$ or number of gates input. |
| MAX | Maximum output voltage value. The default is undefined, and sets no maximum value. |
| MIN | Minimum output voltage value. The default is undefined, and sets no minimum value. |
| n+/- | Positive or negative node of a controlled element. |
| NDIM | Number of polynomial dimensions. If POLY(NDIM) is not set, a one-dimensional polynomial shall be assumed. NDIM must be a positive number. |

NPDELAY Sets the number of data points to use in delay simulations. The default value is the larger of either 10, or the smaller of TD/tstep and tstop/tstep. That is,


The .TRAN statement specifies tstep and tstop values.

LEVEL $=x \quad$ Interchangeable function token such as VCCS, VCAP, etc.

OPAMP or Level=1
or Level=1

P0, P1 ... The polynomial coefficients.
If only one coefficient is specified, the simulation engine shall assume it to be $\mathrm{P} 1(\mathrm{PO}=0.0)$, and that the element is linear. If more than one polynomial coefficient is specified, the element shall be assumed nonlinear, and P0, P1, P2 ... shall be assumed to represent them.

POLY Token for the polynomial function. If POLY (ndim) is not specified, the engine shall assume a one-dimensional polynomial. ndim must be a positive number.

PWL Token for the piecewise linear function.

SCALE Multiplier for the element value.

TC1,TC2 First-order and second-order temperature coefficients. Temperature changes update the SCALE:

SCALEeff $=$ SCALE $\oplus(1+T C 1 \oplus \otimes t+T C 2 \oplus \otimes t 2)$

Token for the time (propagation) delay.

## 13. Best Practices

This section details syntax recommendations for ensuring maximum compatibility with existing proprietary SPICE variants. While not requirements for IBIS-ISS, following these practices will help maintain the portability of IBIS-ISS files.

- Scaling of interconnect subcircuits may give different results between different simulators and should be avoided.
- Global parameters may give different results between different simulators and should be avoided.
- Exponent range should be limited to between e-60 and e+60.
- For maximum compatibility, IBIS-ISS does not support the "X" (Meg) scale factor..
- A name field should begin with [a-z] or [A-Z]. The remaining characters of a name field should be limited to
o [a-z], [A-Z], [0-9], ~!@\#\%\&_<>?[]]:;
- Parameter names should begin with [a-z] or [A-Z], and the remaining characters should be limited to
o [a-z] or [A-Z], [0-9], ! \# \$ \% [ ]
- While a parameter may be defined in more than one .param statement within a subckt, this practice is best avoided.
- Node names should either be all numeric [0-9], or be a name nield.

